# NSPM5131

## ESD Protection Diode Low Clamping Voltage

#### Features

- Unidirectional High Voltage ESD Protection
- Provides ESD Protection to IEC61000-4-2 Level 4: ±30 kV Contact Discharge
- IEC 61000-4-5 (lighting)
- High Voltage Zener Diode Protects Supply Rail up to 160 A (8/20 µs)
- These Devices are Pb-Free and are RoHS Compliant

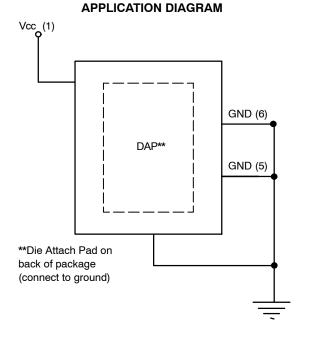


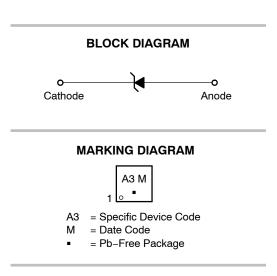
### **ON Semiconductor®**

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UDFN6 CASE 517CS





#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>	
NSPM5131MUTBG	UDFN6	3000/Tape &	
	(Pb-Free)	Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

#### Table 1. PIN DESCRIPTIONS

	4–Channel, 6–Lead, UDFN–8 Package					
Pin	Name	Туре	Description			
1	V <sub>CC</sub>	$HV V_{DD}$	HV ESD Channel			
2	N/C		No Connect			
3	N/C		No Connect			
4	N/C		No Connect			
5	GND		Ground			
6	GND		Ground			
7	GND		Ground			
8	GND		Ground			

#### **ELECTRICAL CHARACTERISTICS**

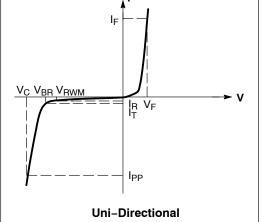
Symbol	Parameter				
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current				
V <sub>C</sub>	Clamping Voltage @ IPP				
V <sub>RWM</sub>	Working Peak Reverse Voltage				
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>				
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>				
Ι <sub>Τ</sub>	Test Current				
$\Theta V_{BR}$	Maximum Temperature Coefficient of VBR				
١ <sub>F</sub>	Forward Current				
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>				

#### (Pins Down View) (Pins Up View) 1 2 3 4 65 XX M 8 7 Pin 1 Marking 23 5 1 4 6 6-Lead UDFN 1c

Top View

**PACKAGE / PINOUT DIAGRAMS** 

Bottom View



#### SPECIFICATIONS

#### Table 2. MAXIMUM RATINGS

Parameter	Rating	Units
Operating Temperature Range	-55 to +125	°C
Storage Temperature Range	-65 to +150	°C
Peak Current (t <sub>p</sub> = 8/20 μs)	160	А

Stresses at or above those listed in Maximum Ratings table may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Also, due to variations in test equipment, stresses shown above are averages.

#### **ELECTRICAL CHARACTERISTICS**

	V <sub>RWM</sub> (V			Breakdown Voltage			<b>V<sub>C</sub> @ I<sub>PP</sub></b> <sub>(8 x 20 μs)</sub> (Note 3)		
	Device	(Note 1)	I <sub>R</sub> @ V <sub>RWM</sub> (μΑ)	R @ V <sub>RWM</sub> (μΑ) V <sub>BR</sub> V (Note 2) @ I <sub>T</sub> (mA		@ I <sub>T</sub> (mA)	V <sub>C</sub> (V)	I <sub>PP</sub> (A)	
	Marking	Max	Max	Min	Nom	Max		Max	
NSPM5131	A3	13.5	1	13.6	15.5	17.5	1	21.5	100

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

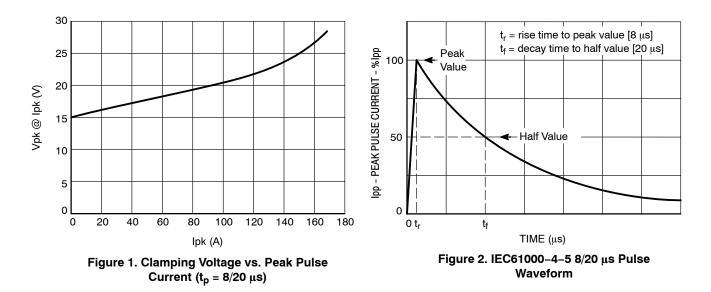
1. A transient suppressor is normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal to or greater than the DC or continuous peak operating voltage level.

2. V<sub>BR</sub> measured at pulse test current I<sub>T</sub> at an ambient temperature of 25°C.

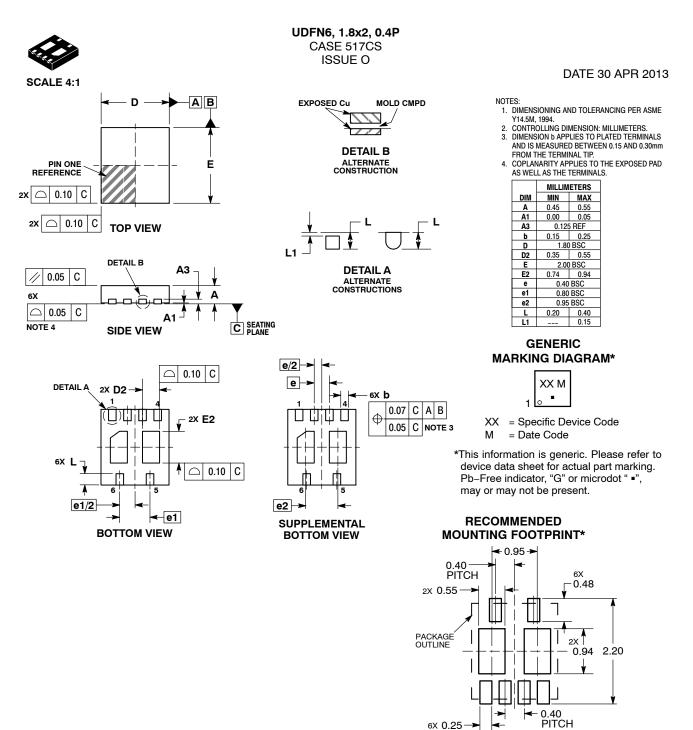
3. Surge current waveform per Figure 2.

#### NSPM5131

#### **TYPICAL CHARACTERISTICS**







\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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